

Celebrating 30 YEARS of Excellence in Advancing Power Semiconductor Technologies

ISPSD is the premier forum for technical discussions in all areas of power semiconductor devices and power integrated circuits, including but not limited to device physics, modeling, design, fabrication, materials, packaging and integration, device reliability, and device/circuit interactions.

The conference will offer a number of one-hour short courses to registered attendees. Each short course, delivered by an expert in his or her topic area, addresses the need for an indepth discussion of important power semiconductor device or power IC design issues, as well as their applications.

The submitted proposal should include the following:

- Contact information for presenting speaker: name, affiliation, mailing address, telephone number, and email address.
- An abstract of no more than 200 words describing what is to be presented, including whether the topic will be treated in-depth or as a survey, and the level of the intended audience (entry level, intermediate, or advanced). This abstract should be in a form suitable for publication in the ISPSD advance program.
- A short biography (<200 words) of each speaker.

Examples of past short course topics can be found on our website at **www.ispsd2018.com**. Please email your proposal submission to the Short Course Chair, Dr. Alex Huang.

VENUE:

Palmer House Hilton Chicago, USA May 13-18, 2018 ISPSD2018.COM

Proposal submission deadline:

October 30, 2017

Speaker notification:

December 15, 2017

Honorarium:

\$2,000

General Chair:

Professor Z. John Shen Illinois Institute of Technology, USA Email: johnshen@ieee.org

Short Course Chair:

Professor Alex Huang University of Texas at Austin Email: aqhuang@utexas.edu

ISPSD 2018 is sponsored by the IEEE Electron Device Society (EDS) and technically co-sponsored by the IEEE Power Electronics Society (PELS) and the IEEE Industry Applications Society (IAS)







